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Theoretical Studies of Electron Transport in Quantum-Well Structures

by

Lakshmi N. Pandey, Mark I. Stockman, Thomas F. George and Devaraj Sahu

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Departments of Chemistry and Physics
State University of New York at Buffalo
Buffalo, New York 14260

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Theoretical Studies of Electron Transport in Quantum-Well Structures

Lakshmi N. Pandey,* Mark I. Stockman,*[†] Thomas F. George*[†] and Devaraj Sahu**

* Departments of Physics & Astronomy and Chemistry

Center for Electronic and Electro-optic Materials

State University of New York at Buffalo, Buffalo, New York 14260, USA

** Computer Sciences Corporation, 10110 Aerospace Road

Lanham-Seabrook, Maryland 20706, USA

The study of resonant tunneling structures (RTS) has become increasingly important because of possible device applications and also because of the basic physics they involve. Within the static picture we have calculated the dwell time, i.e., the average time an electron spends inside an RTS. The actual time involved in the tunneling process can be described by the solution of the time-dependent effective mass Schödinger equation (TDEMSE), and a code based on the fast Fourier transform method is developed to solve the TDEMSE for a potential profile such as RTS. The physical properties of an RTS investigated are the build-up time, which is the time taken by an electron to accumulate probability inside the well, and the escape time.

1. Introduction

How long it takes for a moving particle to penetrate a potential barrier is a question being asked often since the discovery of alpha particles. Recently, interest in investigating the time scale involved in the tunneling process was revived after the work of Tsu and Esaki,¹ where they explained the negative differential resistance in the $I - V$ characteristic of a compound semiconductor diode through the resonant tunneling process. Since then, several static and dynamical physical properties of resonant tunneling structures (a single well formed by two barriers of finite widths and heights,² henceforth referred to as RTS) have been the subject of investigation. A vast literature^{3,4} is available by now on the field. Our main interest here is to answer the question above, although the time scale involved in the resonant tunneling process is the most controversial topic still today. We have studied through a static picture the most accepted dynamical quantity, the dwell-time, which is the average time spent by an electron inside an RTS. A dynamical aspect of the problem is also addressed by the solution of the one-dimensional time dependent effective mass Schrodinger equation (TDEMSE), and the properties investigated from the solution are the build-up time, which is the time taken by an electron to accumulate probability inside the well, and the escape time, which is on a time scale associated with the resonance width through the uncertainty principle.

2. Static Picture and Dwell-Time

As mentioned above, the dwell time is an average time during which the probability to find the electron inside an RTS is finite. Hence, the dwell time is the total probability of the electron per unit incident flux.⁵ The stationary-state properties of an RTS in the effective mass approximation are obtained by solving the time-independent Schrodinger equation for the envelop function $\Psi(x)$ along the growth direction x :^{6,7}

$$-\frac{1}{\hbar^2} m^a \frac{d}{dx} m^b \frac{d}{dx} m^a \Psi(x) + [V(x) - E] \Psi(x) = 0 \quad , \quad (1)$$

where $V(x)$ is the RTS potential profile

$$V(x) = \begin{cases} V_1, & \text{if } 0 \leq x \leq a_1, \\ 0, & \text{if } a_1 \leq x \leq a_1 + d, \\ V_2, & \text{if } a_1 + d \leq x \leq a_1 + d + a_2, \end{cases}$$

V_i and a_i ($i=1,2$) are the heights and widths of the barriers, d is the width of the well, m is effective mass, and $2a + b = -1$ with a and b as constants. These constants must appear in the form given in order to keep the Hamiltonian Hermitian. The kinetic energy operator of Eq. (1) dictates that $m^a \Psi(x)$ and $m^{a+b} \frac{d\Psi(x)}{dx}$ must be continuous across the interface, implying the physical result that the current density $j \propto \frac{\Psi^*}{m} \frac{d\Psi}{dx} = m^a \Psi^* m^{a+b} \frac{d\Psi}{dx}$ be continuous. However, in general, the charge density $\rho \propto \Psi^* \Psi$ need not be continuous across an interface. For the special case of $a = 0$ and $b = -1$ one obtains, in addition, the continuity of charge density. So, this is a single-parameter b ($a = -\frac{1+b}{2}$) problem. The resonance states clearly depend on this parameter b , and one can not, *a priori*, prefer one value of b over another.

We have studied the dependence of the dwell time and width of the resonance on b . The dwell time τ_D over the region of 0 to x_1 of the structure is defined⁴ as the integrated probability density of the electron per unit incidence flux,

$$\tau_D = \frac{m}{\hbar k} \int_0^{x_1} dx |\Psi(x)|^2, \quad (2)$$

where $k = \sqrt{\frac{2mE}{\hbar^2}}$. Figures 1 and 2, and 3 and 4 show the dwell time as a function of x for three different b parameter values, -2, 0 & 2, and width of the resonance as a function of b for the first and second resonance states, respectively. It is clear from Figs. 1 and 3 that the dwell time varies considerably as one changes b , but a reverse pattern is found (Figs. 2 and 4) in the change of resonance widths of the first and second resonances.

We have thus shown that the parameter associated with the boundary conditions has a profound effect on the characteristics of the system such as resonance energy and width, and dwell time. It has been shown⁸ in a different context that for two semi-infinite heterostructures, the boundary conditions at the interface not only involve the effective masses but also certain other parameters which are microscopic in origin, having no macroscopic analogs. We therefore believe that the arbitrariness in the choice of the parameter b can be fixed through microscopic calculations.

2. Dynamic Picture and Build-up and Escape Times

For $b=0$ and constant mass throughout the RTS, Eq. (1) with $E = i\hbar \frac{\partial}{\partial t}$ is solve numerically with the fast Fourier transform method.⁹ When using this method, it has been found convenient to model a discontinuous potential, such as an RTS, as a combination of Fermi distribution functions of the form

$$\begin{aligned} \frac{V(x)}{V_0} = & \frac{1}{\exp[(x - x_0 - c/2)/\delta] + 1} - \frac{1}{\exp[(x - x_0 + c/2)/\delta] + 1} \\ & - \frac{1}{\exp[(x - x_0 - d/2)/\delta] + 1} + \frac{1}{\exp[(x - x_0 + d/2)/\delta] + 1}, \end{aligned} \quad (3)$$

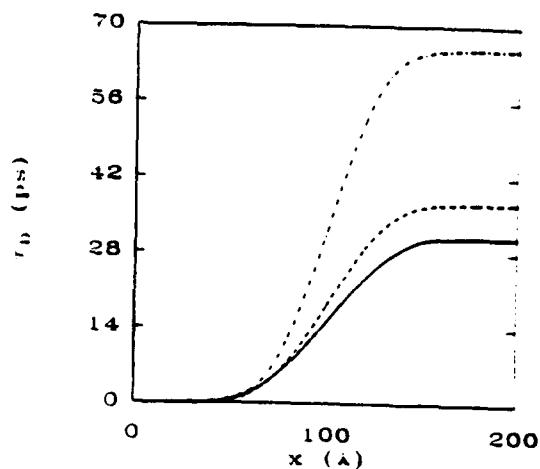


Fig. 1. Dwell-time as a function of position x for the first resonance state. The solid, dashed and dot-dashed lines are for $b = -2, 0$ and 2 , respectively. The other parameters are: $a_1 = a_2 = 50$ Å, $d = 100$ Å.

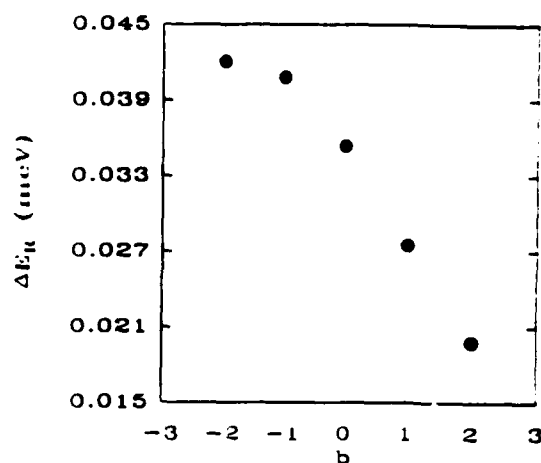


Fig. 2. Width of the first resonance state as a function of b .

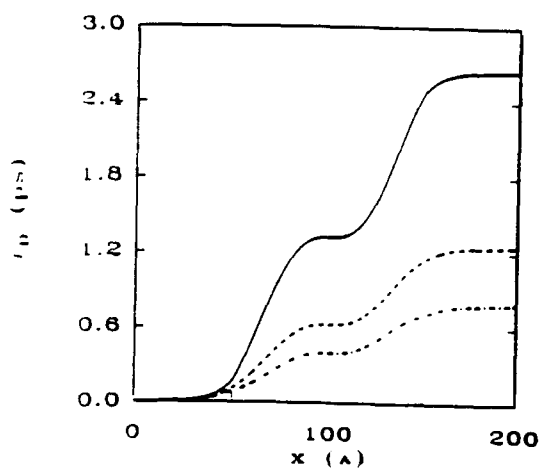


Fig. 3. Same as in Fig. 1 but for the second resonance state.

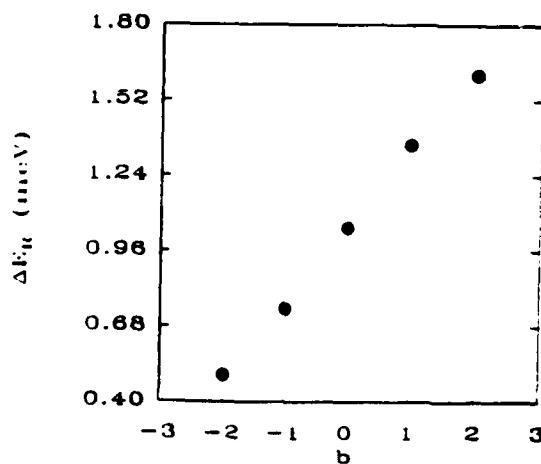


Fig. 4. Width of the second resonance state as a function of b .



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where, $V_0 = V_1 = V_2$ is the barrier height, $c = a_1 + d + a_2$ is the total length of the RTS, x_0 is the position of the middle of the RTS, and δ is a smoothing parameter. We have carried out a single-step calculation using 1024 grid points, 20 out of which are used to discretize the RTS, with 10 out of this 20 to discretize the well in the RTS. Here δ is taken to be 2 Å, and a box of length 10240 Å corresponding to a grid spacing of 10 Å has been chosen for this calculation. These parameters are found appropriate to demonstrate the dynamics of an electron in a box which has a symmetric RTS located at its center.

To study the transport properties of an electron, we have chosen its initial wavefunction to be represented by a Gaussian wavepacket,

$$\Psi(x, t = 0) = N \exp\left[\frac{-(x - x_p)^2}{4\sigma^2} + ik_0 x\right], \quad (4)$$

where x_p is the center of the wavepacket (one fourth of the box length from the left wall), σ is the width of the wavepacket, k_0 is the mean wave vector ($\Delta k = \frac{1}{\sigma}$), and N is a normalization factor. The wavefunction $\Psi(x, t)$ has been calculated for different values of t .

A symmetric RTS with $c = 200$ Å, $d = 100$ Å and $V_0 = 200$ meV is analyzed. There are two resonance states at 30.87 ± 0.174 meV and 117.4 ± 2.98 meV of the RTS considered here. Figures 5 and 6 display the integrated probability density $P(t) = \int_{x_0-d/2}^{x_0+d/2} dx |\Psi(x, t)|^2$ inside the well, which is part of the wavefunction trapped in the well as a function of time for the first and second resonance states, respectively. The transmission probability $T(t) = \int_{x_0+c/2}^{\infty} dx |\Psi(x, t)|^2$ is also shown in Figs. 5 and 6 by dotted lines. It is clear that $P(t)$ increases up to a certain value P_{max} , and the time taken to reach P_{max} from a reference point is called the buildup-time τ_b . The probability $P(t)$ decays exponentially after the build-up time, and an exponential fit to the decay part of $P(t)$ versus time, $P(t) = P_{max} \exp(-\theta t)$, yields $\theta = 0.264$ and 4.5 ps^{-1} and hence, the width of the state $\Delta E_R = 0.174$ and 2.98 meV for the first and second resonance states, respectively. Since the first resonance state is sharp in energy, it takes more time to decay, during which the reflected and transmitted parts of the wavepacket return back from the box wall. To avoid interferences with the returned reflected and transmitted parts of the wavepacket, instead of allowing $P(t)$ to decay further, a fitted curve is shown by the dot-dashed line in Fig. 5.

In Figure 7, we show (a) the maximum probability density P_{max} trapped in the well in the upper panel and (b) the transmission probability along with the plane wave transmission coefficient (solid line) in the lower panel as a function of the electron energy in the neighborhood of the second resonance state for $\sigma = 400$ (solid circles), 500 (open circles) and 600 (solid triangles) Å. The lower panel also displays the exact transmission coefficient T^σ for a wavepacket¹⁰ with $\sigma = 400$ (dashed line), 500 (dotted line) and 600 (dot-dashed line) Å. The resonance energy of $T(t)$ in the lower panel of Fig. 7 is slightly shifted from the T^σ because of the reason that the Fermi distributed structure as in Eq. (3) is not an exact representation of the RTS used to calculate the plane wave transmission coefficient and T^σ . The transmission probability $T(t)$ associated with the dynamics and exact transmission coefficient T^σ are expected to coalesce with the plane wave transmission coefficient in the limit of an infinitely-extended ($\sigma \rightarrow \infty$) wavepacket. The distribution P_{max} as a function of energy peaks at the resonance energy, and the width (FWHM) of this

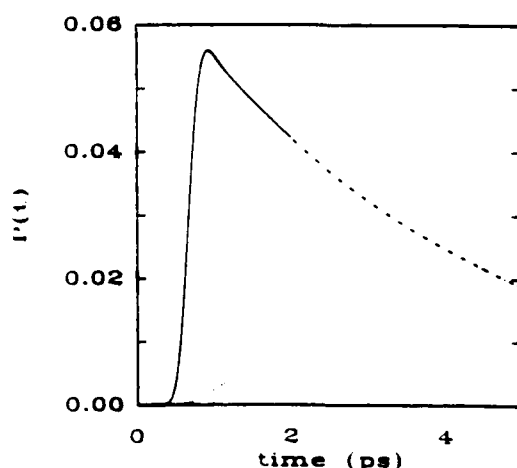


Fig. 5. Integrated probability $P(t)$ inside the well as a function of time. The mean energy and width of the incident packet are the energy of the first resonance state and 400 Å, respectively. The dot-dashed line is an extrapolation of $P(t)$.

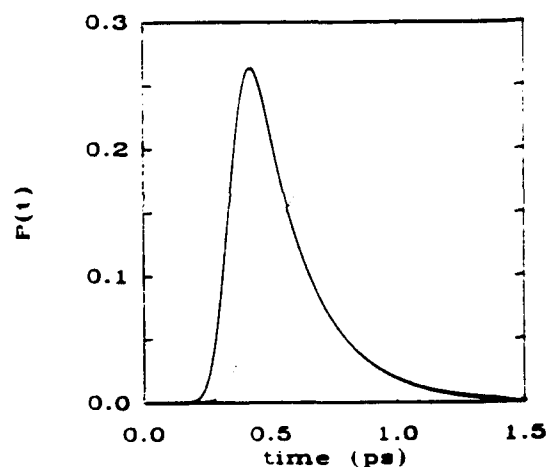


Fig. 6. Integrated probability $P(t)$ inside the well as a function of time. The mean energy and width of the incident packet are the energy of the second resonance state and 400 Å, respectively.

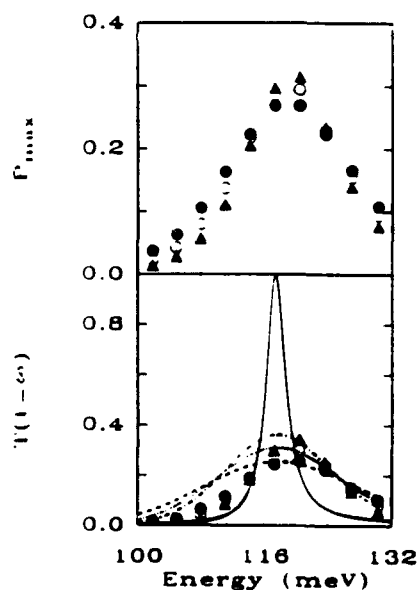


Fig. 7. P_{max} in the upper panel and $T(t = \infty)$ in the lower panel as a function of the mean energy. The solid line shows the plane wave transmission coefficients. The dashed, dotted and dot-dashed lines in the lower panel are T^σ for $\sigma = 400, 500$ and 600 Å, respectively. The solid circles, open circles and solid triangles represent the results of $\sigma = 400, 500$ and 600 Å, respectively.

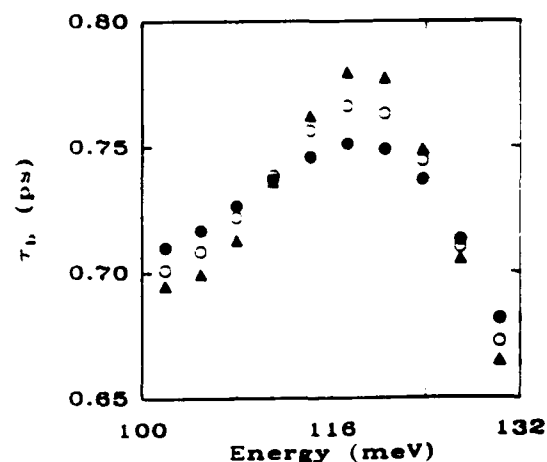


Fig. 8. Build-up time as a function of the mean energy. The explanation of the points is the same as in Fig. 7.

distribution decreases as σ increases. This is a consequence of resonant tunneling, because for the case of on-resonance scattering, a substantial portion of the wavepacket tunnels through the first barrier, whereas for off-resonance, most of the packet gets reflected by the first barrier.

The resonance tunneling process can further be demonstrated by looking at τ_b as a function of packet mean energy, as displayed in Fig. 8 for energies in the vicinity of the second resonance state and $\sigma = 400, 500$ and $600 \text{ \AA}$. This τ_b also peaks at the resonance energy, which can not be explained through simple dynamics but must involve the resonance tunneling. In a simple dynamical picture, energetic the particle takes less time to travel a path filled with obstacles (repulsive potential profile such as an RTS), whereas in the case of resonance tunneling, the electron with energy equal to the resonance energy bounces back and forth from the walls of the well, since its wavefunction is negligible at the walls in comparison with the rest of the places in the well, and it takes much more time to accumulate probability than the electrons with energies off-resonance.

In conclusion, we have shown here a dynamical picture of a resonance tunneling process. The probability inside the well decays exponentially, and excellent agreement is found between the decay constant and the static width of the resonance. We have also demonstrated that the transmission probability coalesces with the plane wave transmission coefficient in the limit of an infinitely-extended wavepacket.

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12

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